of BaP and 6-CH₃-BaP as reported above are seen to parallel the behavior of anthracene. The observed cation radical from BaP is found to be the 6-CF₃CO₂-BaP cation radical formed most probably by the following sequence of steps (eq 2). The ap-

$$BaP \xrightarrow{-1e^-} BaP^+ \xrightarrow{CF_3CO_2^-} 6-CF_3CO_2 - BaP \xrightarrow{-1e^-} 6-CF_3CO_2 - BaP^+ (2)$$

pearance of a single major product in the HPLC separation of the reaction products,⁴ due to the 6-(trifluoroacetoxy)benzo[a]pyrene, is further proof of the identity of the observed cation radical. A similar reaction pathway has been previously proposed¹⁸ for the reaction of BaP with manganic acetate in acetic acid in which the major product is 6-acetoxybenzo[a]pyrene.

6-CH₃-BaP is much less reactive in TTFA/TFA; the substitution of the methyl group in the position of highest electron density considerably retards the substitution reactions, the oneelectron oxidation product of 6-CH₃-BaP being relatively stable for several hours at reduced temperatures. Reaction is not, however, completely elminated; the 6-CH₃-BaP⁺ EPR spectrum decays appreciably at room temperature, and a variety of reaction products consistent with both methyl and ring substitution by trifluoroacetoxy groups are found.⁴ These results again parallel the behavior seen by 6-CH₃-BaP in manganic acetate-acetic acid mixtures.18

Reactions in H₂SO₄. The reactions of 6-CH₃-BaP and 6-F-BaP observed in H_2SO_4 may be of some significance to proposed metabolic pathways for these compounds. Cavalieri² has proposed that cation radicals can be generated from polycyclic hydrocarbons by one-electron oxidation with a Fe(V) form of cytochrome P-450. That such a reaction could occur is evidenced by the one-electron oxidation of methylarenes with tris(phenanthroline)iron(III)

complexes in TFA.¹⁹ It was further proposed that the cation radicals would then react with nucleophiles, including DNA, at the positions of highest charge density. The metabolic formation of quinones^{2,20} from 6-F-BaP is hypothesized to proceed via a cation radical intermediate which is then attacked by a nucleophilic oxygen atom. Adducts of 6-F-BaP to DNA in model systems have also been identified which are consistent with the reaction at the 6-position of BaP. Circumstantial evidence for the intermediacy of cation radicals in the metabolism of 6-CH₃-BaP comes from the identification of adducts in a variety of systems in which the BaP-6-CH₂ group is bound to the 2-amino group of guanine,²¹ and the formation of 6-CH₂OH-BaP as a major product of metabolism.22

Our studies seem to have demonstrated rather directly that the formation of a cation radicals from 6-CH₃-BaP and 6-F-BaP could lead to the observed reaction products. In H₂SO₄, the first produced one-electron oxidation products appear to react with residual water to give 6-CH₂OH-BaP⁺ and 6-OH-BaP⁺, the former yielding 6-CH₂OH-BaP on workup and the latter autoxidizing on workup to give the three benzo[a] pyrenequinones (1,6-, 3,6-, and 6,12-).

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A Theoretical Survey of Singly Bonded Silicon Compounds. Comparison of the Structures and Bond Energies of Silyl and Methyl Derivatives

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Abstract: The silicon hydrides, SiH_n (n = 1-4), and the entire set of H₃SiX (X = Li, BeH, BH₂, CH₃, NH₂, OH, F and Na, MgH, AlH₂, SiH₃, PH₂, SH, Cl) molecules have been investigated by using ab initio methods. All structural parameters were optimized by use of the 3-21G and 3-21G^(*) basis sets. The silvl derivatives are compared with the corresponding methyl compounds. In most cases, the equilibrium geometries of the methyl and silyl molecules are similar. The most notable exception is in silylamine, where a planar geometry is found about the nitrogen. Addition of d-functions to the second-row atoms results in a decrease in the bond lengths. The relative H_3Si-X and H_3C-X bond energies depend principally on the electronegativity of the group X. Since SiH₃ has a higher electron affinity and a lower ionization potential than CH₃, groups which are very electronegative or very electropositive have stronger bonds to silicon than carbon.

Silicon, although a contiguous group 4 (group 14 in the more recent notation) element,¹⁷¹ often frustrates chemists in their search for analogues of carbon compounds.^{2,3} Difficulties in studying many silicon singly bonded species are often attributed to the

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Table I. HF/3-21G Energy, Zero-Point Energy, ZPE, HF/3-21G(*) and MP4/6-31G* Total Energies, and Relative Energy, RE, for All Silicon Compounds^a

molecule	sym	state	HF/3-21G	ZPE ^b	HF/3-21G ^(*)	MP4SDTQ/6-31G*	RE ^c
SiH	C	² 11	-287.907 21	2.9 [0]	-287.971 42	-289.482.24	0.0
SiH	C _w	⁴ Σ ⁻	-287.878 56	3.2 [0]	-287.938 14	-289.428 23	34.1
SiH,	C_{2r}	${}^{1}A_{1}$	-288.484 29	7.5 [0]	-288.56028	-290.089 96	0.0
SiH,	C_{2r}	³ B ₁	-288.48090	7.9 [0]	-288.55363	-290.064 34	16.4
SiH,	D_{wv}	${}^{3}\Sigma_{n}^{-}$	-288.44574	6.7 [2]	-288.50832	-290.023 95	40.5
SiH,	$D_{\pi r}$	$^{1}\Delta_{n}^{"}$	-288.37436	8.1 [1]	-288.43606	-289.970 92	75.1
SiH,	C_{w}	${}^{2}A_{1}$	-289.080 54	13.8 [0]	-289.166 16	-290.69572	0.0
SiH	D_{3h}	${}^{2}A_{2}''$	-289.072 49	12.8 [1]	-289.15399	-290.687.06	4.4
SiH₄	T_d	$^{1}A_{1}$	-289.68698	20.2 [0]	-289.784 26	-291.33126	
H ₃ SiLi	$\tilde{C_{3v}}$	¹ A ₁	-296.509 92	15.1 [0]	-296.590 96	-298.19680	
H ₃ SiBeH	C_{w}	$^{1}A_{1}$	-304.231 69	20.7 [0]	-304.318 44	-305.991 75	
H ₃ SiBH ₂	C_{s}^{n} 1 ^d	¹ A ⁷	-314.783 31	28.5 [0]	-314.87668	-316.65168	0.0
H ₃ SiBH ₂	$C_s, 3^d$	¹ A′	-314.78329	28.4 [1]	-314.87665	-316.65169	-0.1
H ₃ SiCH ₃	$C_{3v}, 4^{d}$	${}^{1}A_{1}$	-328.52612	40.5 [0]	-328.62274	-330.52462	0.0
H ₃ SiCH ₃	C_{3v} , 5 ^d	$^{1}A_{1}$	-328.52432	40.5 []]	-328.620 47	-330.52222	1.5
H ₃ SiNH ₂	$C_s, 3^d$	¹ A ⁷	-344.450 39	33.3 [0]	-344.55548	-346.559 84	0.0
H ₃ SiNH ₂	$C_s, 1^d$	¹ A′	-344.450 35	33.2 [1]	-344.55548	-346.559 93	-0.2
H ₃ SiOH	$C_s, 6^d$	¹ A′	-364.18060	25.2 [0]	-364.293 37	-366.41442	0.0
H ₃ SiOH	$C_s, 7^d$	¹ A′	-364.17980	24.8 [1]	-364.292 64	-366.41308	0.4
H ₃ SiF	C_{3v}	${}^{1}A_{1}$	-388.07406	18.1 [0]	-388.193 34	-390.42277	
H ₃ SiNa	C_{3v}	$^{1}A_{1}$	-449.968 32	14.6 [0]	-450.051 28	-452.58707	
H ₃ SiMgH	C_{3v}	$^{1}A_{1}$	-488.15240	18.7 [0]	-488.259 54	-490.947 98	
H ₃ SiAlH ₂	$C_s, 3^d$	$^{1}A'$	-530.84548	24.0 [0]	-530.99088	-533.86663	0.0
H ₃ SiAlH ₂	$C_s, 1^d$	¹ A′	-530.84548	24.0 [1]	-530.990 88	-533.866 63	0.0
H ₃ SiSiH ₃	D_{3d}	${}^{1}A_{1g}$	-578.241 21	31.9 [0]	-578.427 52	-581.508 28	0.0
H ₃ SiSiH ₃	D_{3h}	${}^{1}A_{1}^{7}$	-578.23993	31.8 [1]	-578.426 09	-581,506 63	0.9
H ₃ SiPH ₂	$C_s, 1^d$	$^{1}A'$	-629.26570	27.5 [0]	-629.465 45	-632.76015	0.0
H ₃ SiPH ₂	$C_s, 2^d$	¹ A′	-629.264 02	27.4 [1]	-629.463 21	-632.759 85	0.1
H ₃ SiPH ₂	$C_s, 3^d$	¹ A′	-629.23071	26.6 [1]	-629.424 52	-632.72041	24.0
H ₃ SiSH	$C_s, 6^d$	$^{1}A'$	-685.277 10	22.0 [0]	-685.48790	-689.00745	0.0
H ₃ SiSH	$C_s, 7^d$	¹ A′	-685.27585	21.8 [1]	-685.48617	-689.005 65	0.9
H ₃ SiCl	C _{3v}	¹ A ₁	-746.45779	17.0 [0]	-746.66985	-750.423 00	

^a The Hartree-Fock and MP4 total energies are in hartrees while the ZPE and RE are in kcal/mol. ^b The number in brackets is the number of imaginary frequencies. ^c The relative energy is determined by differencing the MP4 total energies and correcting for changes in the ZPE. ^d The bold face numbers refer to figures given in the text.

involvement of Si d-orbitals. These orbitals are low enough in energy to be available for bonding. Pentacoordinate transition states with relatively low activation energies give rise to reaction pathways not accessible to carbon.⁴ Some small molecules with singly bonded silicon are known; these include the silicon hydrides SiH_n (n = 1-4), methylsilane, fluoro- and chlorosilane, and the silanols. However, many of the other possible silyl compounds are not known experimentally. In order to explore single bonds involving silicon in a systematic manner, a theoretical examination of the energies and geometries of the full set of silyl compounds H_3SiX (X = Li, BeH, BH₂, CH₃, NH₂ OH, F and Na, MgH, AlH₂, SiH₃, PH₂, SH, Cl) is presented. The silicon hydrides are also examined. Emphasis is laid on a comparison between corresponding silicon and carbon compounds.

An earlier paper investigated the role of d-orbitals on normal valent silicon molecules.⁵ When d-functions were added to the minimal STO-3G basis,⁶ the structural description of nonhypervalent species was not improved significantly. We now employ the split valence 3-21G and also the $3-21G^{(*)}$ basis sets.^{7,8} The latter includes a set of six Gaussian d-orbitals on all second-row

atoms. These results allow the investigation of Si species for which there is insufficient experimental knowledge. Most of the corresponding methyl compounds have been calculated previously at various levels.⁷⁻¹⁰ Since our primary goal is to compare the lowest energy equilibrium structures of saturated silyl molecules with those of their methyl counterparts, only the singlet potential energy surfaces were examined. For the lower silicon hydrides, states of different spin multiplicity were calculated. We first determine the most stable equilibrium structure, and then obtain information on the energies of rotation about the silicon-heavyatom bond.

Computational Method

All molecular geometries were fully optimized by minimization of the Hartree-Fock energy within prescribed symmetry constraints. Singlet states were examined with spin-restricted (RHF) theory,¹¹ while spin-unrestricted (UHF) theory¹² was used for states of higher multiplicity. Population analyses were based on the Mulliken method.¹³ The geometries were determined by using the 3-21G (no d-functions) and the $3-21G^{(*)}$ (d-functions on all second-row atoms) basis sets.^{7,8} The two basis sets are coincident for molecules with only first-row atoms. To determine whether the optimized geometry represents a local minimum on the potential energy surface or a transition structure, the force constant matrix was constructed for all molecules at the 3-21G optimized geometry. Diagonalization of this matrix yields the vibrational frequencies for normal mode harmonic motions. Extensive comparisons with experiment¹⁴ have shown that these harmonic frequencies are generally about 11% too large; the error decreases with correlation.¹⁵

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Table II. HF/3-21G Energy, Zero-Point Energy, ZPE, HF/3-21G^(*) and MP4/6-31G* Total Energies, and Relative Energy, RE, for All Carbon Compounds^a

molecule	sym	state	HF/3-21G	ZPE ^b	HF/3-21G ^(*)	MP4SDTQ/6-31G*	RE ^c
СН	$C_{\infty v}$	² Π	-38.05191	4.1 [0]		-38.360 38	0.0
СН	$C_{\infty v}$	$4\Sigma^{-}$	-38.070 56	4.8 [0]		-38.344 62	10.6
CH,	C_{2r}	³ B ₁	-38.70907	11.4 [0]		-39.02089	0.0
CH,	C_{2v}	${}^{1}A_{1}$	-38.651 85	11.0 [0]		-38.993 37	16.8
CH ₂	$D_{\infty r}$	${}^{3}\Sigma_{u}^{-}$	-38.65185	9.9 [2]		-39.009 09	5.9
CH_2	$D_{\infty v}$	$^{1}\Delta_{u}$	-38.60072	12.1 [1]		-38.92944	57.9
CH,	D_{3h}	${}^{2}A_{2}''$	-39.34261	19.5 [0]		-39.68914	
CH₄	T_d	${}^{1}A_{1}^{-}$	-39.97688	30.1 [0]		-40.354 50	
H ₃ CLi	$\tilde{C_{3v}}$	${}^{1}A_{1}$	-46.752 48	22.4 [0]		-47.182 96	
H ₁ CBeH	C_{3v}	${}^{1}A_{1}$	-54.51528	28.5 [0]		-55.01213	
H ₃ CBH ₂	$C_s, 1^d$	¹ A'	-65.078 09	37.2 [0]		-65.681 10	0.0
H ₁ CBH ₂	$C_s, 3^d$	¹ A′	-65.078 01	37.1 [1]		-65.68098	0.0
H,CCH,	D_{3d}	¹ A _{1e}	-78.793 95	50.2 [0]		-79.53215	0.0
H ₁ CCH ₁	D_{3h}	¹ A ₁ ⁷	-78.789 57	50.0 [1]		-79.527 26	2.9
H ₃ CNH ₂	$C_{s}, 1^{d}$	¹ A ⁷	-94.68166	42.7 [0]		-95.537 51	0.0
H ₃ CNH ₂	$C_s, 2^d$	¹ A′	-94.678 50	42.1 [1]		-95.53284	2.3
H ₃ CNH ₂	$C_s, 3^d$	¹ A′	-94.677 93	41.6 [1]		-95.52801	4.8
H ₃ COH	$C_s, 6^d$	¹ A'	-114.398 02	34.2 [0]		-115.372 99	0.0
H ₃ COH	$C_s, 7^d$	¹ A'	-114.39566	33.7 [1]		-115.37064	1.0
H ₃ CF	C_{3v}	${}^{1}A_{1}$	-138.281 89	26.5 [0]		-139.360 13	
H ₃ CNa	C_{w}	${}^{1}A_{1}$	-200.200 30	21.9 [0]	-200.203 16	-201.56984	
H ₃ CMgH	C_{3v}	${}^{1}A_{1}$	-238.41316	26.4 [0]	-238.435 20	-239.947 11	
H ₁ CAlH ₂	$C_s, 3^d$	¹ A ⁷	-281.126 55	32.1 [0]	-281.18281	-282.88095	0.0
H ₃ CAlH ₂	$C_s, 1^d$	¹ A′	-281.126 55	32.0 [1]	-281.18280	-282.88095	-0.1
H ₃ CPH ₂	$C_s, 1^d$	$^{1}A'$	-379.53374	36.2 [0]	-379.641 09	-381.762 32	0.0
H ₃ CPH ₂	$C_s, 2^d$	¹ A′	-379.53110	36.0 [1]	-379.63798	-381.75917	1.8
H ₃ CPH ₂	$C_s, 3^d$	¹ A′	-379.47948	35.2 [1]	-379.575 50	-381.703 98	35.5
H ₃ CSH	$C_s, 6^d$	$^{1}A'$	-435.52629	30.6 [0]	-435.63728	-437.990 98	0.0
H ₃ CSH	$C_s, 7^d$	¹ A′	-435.524 56	30.3 [1]	-435.63512	-437.988 72	-1.1
H ₃ CCl	C_{3v}	¹ A ₁	-496.689 48	25.3 [0]	-496.795 00	-499.38817	

^a The Hartree-Fock and MP4 total energies are in hartrees while the ZPE and RE are in kcal/mol. ^b The number in brackets is the number of imaginary frequencies. ^cThe relative energy is determined by differencing the MP4 total energies and correcting for changes in the ZPE. ^dThe bold face numbers refer to figures given in the text.

examining the number of negative eigenvalues of this matrix (imaginary frequencies), classification (local minimum or transition structure) of the stationary point is possible. Electron correlation effects are assessed by single-point Møller-Plesset perturbation theory at fourth order,¹⁶ carried out with the 6-31G* basis¹⁷ which includes polarization functions on all heavy atoms. Inner shell orbitals are excluded (frozen core approximation). These calculations will be denoted MP4SDTQ/6-31G*//HF/3-21G(*) where "//" means "at the geometry of". All calculations were carried out with the GAUSSIAN 82 program.¹⁸

Results

The Hartree-Fock (HF/3-21G and HF/3-21G^(*)) and correlated (MP4SDTQ/6-31G*) energies for all of the silicon molecules are listed in Table I, together with the zero-point vibrational energies. If more than one structure is calculated for a given molecule, the relative energies also are listed. These are derived from the MP4SDTQ/6-31G*//HF/3-21G(*) energies corrected for the zero-point differences. For comparison, energies for analogous carbon compounds are listed in Table II, calculated in the same manner as in Table I. Optimized geometries are available in the Carnegie-Mellon Quantum Chemistry Archive.¹⁹ Unless otherwise noted, all structural parameters and electron populations for the silicon and carbon second-row molecules quoted below are those obtained with the $3-21G^{(*)}$ basis set.

CH and SiH. Experimentally, the ground state of CH is known to be ² Π (one π -electron).²⁰ As determined from the photoelectron

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spectrum of CH^{-,21} the ${}^{4}\Sigma^{-}$ state (two π -electrons) is 17.1 kcal/mol higher in energy. The results summarized in Table II (10.6 kcal/mol) underestimate this splitting. Adding polarization functions to hydrogen (6-31G** basis¹⁷) results in an MP4SDTQ/6-31G**//HF/3-21G energy separation of 11.1 kcal/mol,¹⁹ after correcting for zero-point energy differences. By use of more extensive 6-311G** basis set²² to generate MP4SDTQ/6-311G** potential energy surfaces, the energy difference between the v = 0 vibrational levels is 12.4 kcal/mol. Extending the basis set and extrapolating the Møller-Plesset series to infinite order result in a 19.5 kcal/mol separation.²⁴ The HF/3-21G C-H bond distance is 1.119 Å, in good agreement with the experimental value of 1.120 Å.²⁰ The bond distance is shorter in the quartet (1.072 Å), in agreement with experiment.²⁰

Silicon monohydride, SiH, is also known to have a ${}^{2}\Pi$ ground state.²⁰ The ${}^{2}\Pi - {}^{4}\Sigma^{-}$ energy separation (MP4SDTQ/6-31G**/ /HF/3-21G^(*)) is 34.8 kcal/mol, after correcting for zero-point energy differences. By analogy with CH, further theoretical refinements are expected to increase this number. It is noteworthy that Park²⁵ has used available spectroscopic results to estimate this splitting to be only 14.2 kcal/mol, in serious disagreement with our results. The SCF results of Bozhenko and Charkin²⁶ yield a separation of 41 kcal/mol, while the CI study of Wirsam²⁷ produced a splitting of 24.0 kcal/mol. Goddard and Harding²⁸

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argued that the GVB Si-H bond strength was greater in the ${}^{2}\Pi$ state by 35 kcal/mol, while Mavridis and Harrison found a splitting of approximately 36 kcal/mol.²⁹ The calculated bond length in the ${}^{2}\Pi$ state is 1.511 Å, in good agreement with the experimental value of 1.520 Å,²⁰ and is longer than the calculated 1.471-Å separation in the ${}^{4}\Sigma^{-}$ state.

 CH_2 and SiH_2 . The bent ${}^{3}B_1$ state of methylene has been thoroughly established by ESR and spectroscopic studies^{30,31} to be the lowest energy structure. The lowest singlet $({}^{1}A_{1}$ with no π -electrons) is higher in energy. Numerous calculations³²⁻³⁹ agree in predicting a triplet ground state. The singlet-triplet separation in CH₂ has long been a subject of controversy,⁴⁰ but it has now been established to be 8.56 \pm 0.09 kcal/mol (T_e value),⁴¹ in agreement with theory^{40,42} and earlier experiments.⁴³⁻⁴⁶ The energy separation presented in Table II is larger (16.8 kcal/mol). Reoptimizing the structures using the 6-31G* basis set and computing the zero-point energies yield a singlet-triplet separation of 13.1 kcal/mol at the MP4SDTQ/6-31G**//HF/6-31G* level.¹⁹ Again, extending the basis set and extrapolating the Møller-Plesset series yield a splitting of 8.2 kcal/mol.²⁴ The H-C-H bond angle (HF/3-21G) is 131.0° in the ³B₁ state, which is smaller than the experimental values of 136°47 and 133.9°.48 In the ${}^{1}A_{1}$ state, the bond angle is only 104.7°, compared to an experimental value of 102.4° ,⁴⁷ better agreement is obtained at the MP2/6-31G* level of optimization.⁴⁹ The bond angle being smaller, the energy difference between the bent and linear structures is larger in the singlet state (41.1 kcal/mol) than in the triplet (5.9 kcal/mol). From experimental data, the barrier to linearity is 5.4 kcal/mol in triplet methylene.⁴⁸

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In contrast to methylene, silylene is known to have a singlet ground state.⁵⁰ This is in agreement with previous ab initio calculations of Wirsam,⁵¹ Meadows and Schaefer,^{35a} and Poirier and Goddard.⁵² This ¹A₁ state is calculated (MP4SDTQ/6-31G*//HF/3-21G^(*)) to be 16.4 kcal/mol more stable than the ³B₁ state of SiH₂. Adding polarization functions to the hydrogen (6-31G** basis) increases the separation to 17.0 kcal/mol at the MP4SDTQ level,¹⁹ after correcting for zero-point energy differences. Assuming that these values again approach the actual energy separation, a conflict could exist between these results and the upper bound value of 14 kcal/mol reported by Lineberger and co-workers.⁵³ The same conclusion has been reached by Schaefer et al.^{35b}

The reversed spin preferences in CH_2 and SiH_2 arise from the magnitude of separation of the highest (a_1) and (b_1) singly occupied orbital energies in the 3B_1 state. In methylene, this energy difference (27 kcal/mol) is considerably smaller than that of silylene (52 kcal/mol). The energy gained in forming a triplet is not enough to compensate for this large energy separation in silylene. Hence, in SiH₂, the 5a₁ orbital is doubly occupied. This singlet character of silylene is also reflected in that of various substituted silylenes.⁵⁴

The calculated SiH₂ bond angle is 93.4° in the singlet, compared to an experimental value of 92.5°,⁵⁵ and 118.0° in the triplet. As these angles are smaller than the corresponding angles of CH₂, the energy separations between the bent and linear structures of SiH₂ are larger. The separation in the singlet (75.1 kcal/mol) is much larger than in the triplet (24.1 kcal/mol).

CH₃ and SiH₃. At the HF/3-21G level, the methyl radical is planar (D_{3h}) ; higher levels agree.^{49,56} Experimentally⁵⁷ there is some evidence for slight nonplanarity due to thermal agitation; Ellison, Engelking, and Lineberger⁵⁸ find a barrier less than one-half of the corresponding zero-point vibrational energy.

There is some doubt about the structure of the silyl radical, as experimental evidence has been presented for both planar⁵⁹ and nonplanar^{60,61} structures. Early theoretical investigations also were inconclusive.^{22,53,62-64} Our results clearly favor a nonplanar pyramidal structure (bond angle 110.9°). The energy of the planar structure (a transition structure for inversion) is 4.4 kcal/mol higher. This value is in good agreement with recent theoretical results of Marynick⁶⁵ and Ohta and co-workers.⁶⁶

CH₄ and SiH₄. Both methane and silane are tetrahedral. The calculated bond length in silane $(1.475 \text{ Å})^8$ agrees well with experiment $(1.481 \text{ Å}).^{67}$ The Si-H bond lengths decrease in the

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order SiH > SiH₂ > SiH₃ ~ SiH₄. Such a smooth trend is not found in the carbon series, either theoretically or experimentally.^{20,47,68a} These results are the direct consequence of the smoothly increasing s character found in the Si-H bonds with increasing number of hydrogens. The s character in the corresponding carbon series does not exhibit this trend. The factors controlling the degree of hybridization in first- and second-row molecules have been discussed in detail by Kutzelnigg.68b

Mulliken populations in the CH_n and SiH_n series reflect the change in polarity in going from carbon to the more electropositive silicon. The partial charge (HF/3-21G) on the hydrogen in CH is +0.127. For the series CH_2 , CH_3 , CH_4 , the charge per hydrogen atom is almost constant (\sim +0.2), resulting in an increase in the negative charge on the carbon atom, up to -0.80 in CH₄. In the silicon hydride series, the situation is reversed. The hydrogen atoms bound to silicon have a partial negative charge, as would be expected by electronegativity arguments, and vary slightly $(HF/3-21G^{(*)})$: SiH (²II) -0.15, SiH₂ -0.15, SiH₃ -0.11, and SiH_4 -0.13. The silicon atom in SiH_4 has a charge of approximately +0.50.

H₃CLi, H₃SiLi, H₃CNa, and H₃SiNa. Silyllithium, produced from the reaction of disilane with lithium hydride in 1,2-dimethoxymethane,⁶⁹ exists as a monomer in solution, in contrast with the tetrameric nature of methyllithium⁷⁰ under similar conditions. Examining the atomic charges in both of the monomers shows that in H_3CLi the lithium atom has a charge of +0.48, while the charge on lithium is +0.43 in H₃SiLi. This agrees with the recent study of the ionicity of X-Li bonds using ⁷Li chemical shifts,⁷¹ which indicates that the charge transfer in C-Li and Si-Li is similar. As expected, the C-Li bond length of 2.001 Å is considerably shorter than the 2.3 Å found experimentally for the methyllithium tetramer,⁷⁰ where each methyl carbon is equidistant to three Li atoms, but agrees well with other calculations.⁷²⁻⁷⁷ The Si-Li bond length (2.542 Å) is shorter than the average separation of 2.68 Å found in crystalline hexameric (trimethylsilyl)lithium.⁷⁸ In H₃SiLi, the H-Si-Li bond angle of 115.1° deviates more from the tetrahedral angle than does the 111.9° H-C-Li angle in H₃CLi. Moreover, the C-H and Si-H bonds lengthen in comparison to unsubstituted methane and silane.

Very soluble monomeric silylsodium has been prepared,^{79,80} but no experimental structural parameters are available. This is also true of monomeric methylsodium, though the tetrameric solid has been examined.⁸¹ The C-Na bond length in the tetramer is 2.58 Å⁸¹ and in crystalline ethylsodium is 2.6 Å,⁸² considerably longer than the calculated bond length of 2.315 Å in isolated H₃CNa. When Na replaces Li in the methyl species, there is an increase in the H-C-H bond angle and a slight decrease in the C-H bond

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length. For the silvl species, there is virtually no change in the H-Si-H bond angle or the Si-H bond length.

H₃CBeH, H₃SiBeH, H₃CMgH, and H₃SiMgH. Silylberyllium hydride, like its monomeric methyl analogue, has not been described, although methylberyllium hydride is known in a coordinated dimeric form.⁸³ The C–Be bond length of 1.698 (5) $Å^{84}$ found in (CH₃)₂Be is quite close to the 1.713-Å separation calculated for monomeric H₃CBeH. The Si-Be separation found in $Be_3Al_2(SiO_3)_6$ is 2.74 Å,⁸⁵ much longer than the 2.204 Å bond length found in H₃SiBeH. However, this comparison involves quite different compounds.

As with methyl- and silvllithium, the direction of charge donation in H_3CBeH and H_3SiBeH is the same. In both molecules there is a loss of electron density on the BeH group, though the charge on the CH₃ group (-0.39) is larger than that on the SiH₃ group (-0.19). The charge on the hydrogen bound to beryllium is approximately the same for both molecules (-0.135), so the drop in electronegativity in replacing carbon with silicon results in a decrease in the positive charge found on beryllium.

Comparison of the results for H_3CLi and H_3CBeH shows that in changing BeH for Li there is a decrease (0.011 Å) in the C-H bond length, with virtually no change in the H-C-H bond angle. In the corresponding silicon compounds, replacing Li with BeH also results in a decrease (0.012 Å) in the Si-H bond length. There is also an increase in the H-Si-H bond angles from 103.3° in H₃SiLi to 107.1° in H₃SiBeH.

Recently, Rosch⁸⁶ isolated the first molecule containing a silyl-magnesium bond, bis(trimethylsilyl)magnesium, although there are earlier reports of analogues of silyl Grignard reagents.⁸⁷ The experimental dimethylmagnesium dimer bridging distance, 2.24 Å,⁸⁸ is longer than the theoretical monomeric single bond length, 2.104 Å. A more pertinent comparison involves the C-Mg bond $(2.16 \text{ Å})^{85}$ in ethylmagnesium bromide.

There is virtually no change in the C-H bond length or the H-C-H bond angle in H₃CBeH and H₃CMgH, but a decrease in the H-Si-H bond angle to 106.0° is found in H₃SiMgH. As expected, the positive charge on magnesium is larger in H₃CMgH than in H₃SiMgH, but no significant change in the Mg-H bond length results. Both Mg-bound hydrogens are partially negatively charged, but the magnitude is larger in H₃SiMgH.

 H_3CBH_2 , H_3SiBH_2 , H_3CAIH_2 , and H_3SiAlH_2 . These H_3XYH_2 compounds are considered in three possible C_s conformations: staggered (1), eclipsed (2), and γ -coplanar (3). While me-



thylborane, H₃CBH₂, is only known experimentally as a dimer,⁸⁹ the monomer has been examined theoretically.⁹⁰ The staggered form 1 is found to be the equilibrium structure (no negative eigenvalues). The conformation around the boron is almost planar, the BH₂ bisector making an angle of 178° with the C-B axis. No stationary point on the potential energy surface is found for the eclipsed conformation 2. The y-coplanar form 3 is the transition structure for the sixfold rotation barrier. After correcting for

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differences in zero-point vibrational energy (Table II), there is no energetic difference between structures 1 and 3, so rotation about the C-B bond bond should be free.

Silylborane is not known experimentally; the closest analogue is F₃SiBF₂.^{91a} The calculated structural features^{91b} are similar to methylborane, the staggered form 1 being the equilibrium structure. The BH₂ bisector is less than 2° out of line with the Si-B axis. No eclipsed conformation 2 of H₃SiBH₂ was found, and y-coplanar 3 is energetically equivalent to the staggered structure at the MP4SDTQ/6-31G* level; rotation is free. The Si-B bond length, 2.025 Å, may be compared to an experimental value of 2.32 Å in 1-Br- μ -(CH₃)₃SiB₅H₇, but this structure has three-center electron-pair bonds.92

There is a reversal in the direction of charge transfer in H₃CBH, and H_3SiBH_2 . In methylborane, a charge of -0.31 is donated to the methyl group, whereas in silylborane, the silyl group has a charge of +0.17. This reflects the changes in electronegativity.

The alanes show properties similar to the boranes, with insignificant sixfold rotational barriers. Methylaluminum hydride monomer exists as a colorless gas,93 but no experimental structure is available. Bridging in dimeric di- and trimethylaluminum compounds has been studied.⁹⁴ Experimental C-Al and Al-H distances in these bridged compounds are 1.947 and 1.676 Å. respectively, as compared to the calculated values of 1.974 and 1.591 Å for the monomeric structure 1. No data appear to be available for silylaluminum hydride. However, the preparation of tris(trimethylsilyl)aluminum,95 following the earlier work of Wiberg and co-workers,⁹⁶ indicates the existence of Si-Al bonds. In both H₃CAlH₂ and H₃SiAlH₂ there is a shift of electron density away from the AlH₂ group. As expected from electronegativity arguments, the charge on the methyl group (-0.35) is larger than the charge on the silvl group (-0.21).

H₃CCH₃, H₃SiCH₃, and H₃SiSiH₃. Several theoretical comparisons of the series H_3CCH_3 , H_3SiCH_3 , and H_3SiSiH_3 have already been published.^{5,97-101} The level of theory presented here yields the same valence orbital energy ordering as that predicted by Liskow and Schaefer,⁹⁸ Nicolas,¹⁰⁰ and Topiol and co-workers¹⁰¹ for several members of the series. In ethane, the a_{1g} orbital is 10 kcal/mol lower in energy than the degenerate e_g orbitals. In methylsilane this order is reversed, with the a_1 orbital 8 kcal/mol higher in energy than the e orbitals. This trend continues in disilane, where the e_g orbitals are considerably lower (43 kcal/mol) in energy than the a_{1g} orbital. This reversal in orbital energy is due to the longer bond lengths involving silicon. The e_e orbitals, antibonding between the two heavy atoms, are bonding to the hydrogens. Increasing the distance between the heavy atoms would tend to stabilize this orbital by decreasing the antibonding contribution. The a_1 orbital involves σ -bonding and becomes considerably destabilized due to loss in orbital overlap. The e_u orbitals which are lower in energy than the a_{1g} and the e_g orbitals also become destabilized at greater heavy atom separations. This is observed in both H₃SiCH₃ and H₃SiSiH₃. These orbitals are pictured below.

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A consequence of this increase in heavy atom separations is a decrease in the rotational barriers. In ethane, the energy difference between the staggered, 4 and eclipsed, 5, forms is 2.9



kcal/mol, in good agreement with the experimental rotational barrier of 2.744 kcal/mol.¹⁰² On passing through the transition structure, C-C bond length increases from 1.542 Å to 1.556 Å and the H-C-C bond angle decreases slightly. In methylsilane, the rotational barrier decreases to 1.5 kcal/mol, in good agreement with the experimental values of $1.7^{103,104}$ and 1.51 kcal/mol.¹⁰⁵ The Si-C bond length increases from 1.883 Å in the staggered form 48 to 1.893 Å in the eclipsed 5. There are only small changes in the bond angles. In disilane, both theory and experiment predict smaller rotational barriers of 0.9 and 1.2 kcal/mol,¹⁰⁶ respectively. On passing through the transition structure, the Si-S distance decreases by 0.010 Å, from 2.3428 to 2.352 Å. In each of these molecules, the calculated heavy-atom-heavy-atom separation is slightly larger than the corresponding experimental value.^{103,107-113}

H₃CNH₂, H₃SiNH₂, H₃CPH₂, and H₃SiPH₂. Methylamine, H_3CNH_2 , has a staggered equilibrium structure, 1. The C-N bond distance, 1.472 Å, is in good agreement with the experimental values (1.471-1.474 Å).^{47,114–116} The calculated C–H (1.082 and 1.090 Å) and N-H (1.004 Å) bond lengths are slightly smaller than the experimental values (1.099 and 1.010 Å, respectively); HF/6-31G* and MP2/6-31G* structures are in better agreement.49 The H-N-C (113.6°) and H-N-H (111.1°) bond angles are slightly larger than the experimental values which range from 110.3° to 112.2° and from 105.8° to 107.1°, respectively. This results in a more planar geometry about the nitrogen than is observed. The eclipsed form, 2 of methylamine is calculated to be 2.3 kcal/mol higher in energy than the staggered structure. The experimental rotational barrier is 1.96 kcal/mol.¹¹⁷ There is virtually no change in the C-N bond distance in 1 and 2, but there is an increase in the bond angles about the nitrogen. In the staggered structure 1, the NH_2 bisector makes an angle with the C-N axis of 135.1° , while in the eclipsed form 2, this angle increases to 141.0° . Y-coplanar methylamine, 3, represents the transition structure for nitrogen inversion. The relative energy is in exact agreement with the experimental inversion barrier of

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4.8 kcal/mol.¹¹⁷ In 3, the C-N bond length decreases to 1.450 Å.

Although silylamine, H₃SiNH₂, is not known, both (CH₃)₃- $SiNH_2^{118}$ and $H_3SiN(CH_3)_2^{117}$ have been studied experimentally. The HF/3-21G and HF/3-21G(*) equilibrium structures of H₃SiNH₂ both predict a planar arrangement about nitrogen, 3, to be the lowest in energy. In the staggered structure 1, the angle between the NH₂ bisector and the Si-N axis is 176.7° (HF/3- $21G^{(*)}$, only a slight deviation from planarity. The energies of 1 and 3 are virtually identical, suggesting free rotation about the Si-N axis. Similar results have been recently reported by Glidewell and Thomson;¹¹⁹ planar arrangements at nitrogen are found in $(SiH_3)_2NH^{120}$ and in $(SiH_3)_3N.^{121}$

Previous theoretical studies of ammonia^{49,122} show that dfunctions are necessary to accurately determine the geometry and inversion barrier. Reoptimization of silvlamine with the 6-31G* basis results in an equilibrium structure with a staggered conformation, 1.¹²³ The y-coplanar structure 3 has one imaginary frequency (HF/6-31G*) and represents a transition structure for rotation. These structures differ in energy by only 0.1 kcal/mol (MP4SDTQ/6-31G*//HF/6-31G* plus HF/6-31G* zero-point correction); rotation about the Si-N axis again is virtually free.¹²³

Methylphosphine, H_3CPH_2 , prefers a staggered geometry, 1. The calculated C-P bond distance, 1.856 Å,⁸ is in good agreement with experiment (1.863 Å).¹²⁴ Recent calculations with the 4-31G* basis¹²⁵ yield slightly better results (1.861 Å). The C-P-H and H-P-H angles are 98.3° and 94.5°, respectively, compared to experimental values of 97.5° and 93.4°.124 The long C-P bond distance counteracts the effect of these small phosphorus bond angles; a rotational barrier of 1.8 kcal/mol, slightly smaller than the rotational barrier found in methylamine, results. The experimental barrier in H_3CPH_2 is 1.96 kcal/mol.^{104,124} In the eclipsed conformation 2, the C-P bond distance increases to 1.868 Å. Due to the small bond angles at phosphorus, the inversion barrier (35.5 kcal/mol) is much larger than in H₃CNH₂. In the y-coplanar structure 3, the C-P bond distance decreases to 1.835 Å.

Silylphosphine, H₃SiPH₂, originally discovered by Jolly and co-workers, 126-128 is the major product of the IR multiphotoninduced decomposition of SiH₄-PH₃ mixtures.¹²⁹ Unlike the amines, the structures of methyl- and silylphosphine are similar. In H_3SiPH_2 , the equilibrium structure also is staggered 1. The calculated Si-P bond distance is 2.256 Å, in good agreement with the experimental value, 2.249 Å.¹³⁰ The bond angles at phosphorus also are small; the Si-P-H and H-P-H values, 96.8° and 95.1°, respectively, are slightly larger than reported experimentally (92.8° and 93.9°).¹³¹ The larger Si-P distance, compared to the C-P bond length, results in a decrease in the rotational barrier in H₃SiPH₂. The calculated barrier of 0.1 kcal/mol is smaller than the experimental value of 1.51 kcal/mol.¹³¹ In the eclipsed

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structure 2, there is the usual increase in the heavy-atom separation (to 2.270 Å). The inversion barrier of silvlphosphine, calculated to be 24.0 kcal/mol, is 11.5 kcal/mol smaller than that in methylphosphine. The decrease in the Si-P separation in the planar structure 3 (to 2.183 Å), larger than in the carbon analogue, may contribute to the inversion-barrier-lowering sterically. However, the principal effect is probably the lower electronegativity of silicon. The phosphorus inversion barrier in LiPH₂ is even smaller, 6.2 kcal/mol at the same level of theory.¹⁹

H₃COH, H₃SiOH, H₃CSH, and H₃SiSH. All these H₃XYH molecules have staggered equilibrium structures, 6. The eclipsed forms, 7, represent transition structures for X-Y bond rotations.



In methanol, the optimized C-O bond length (1.440 Å) and the C-O-H angle (110.4°) are both slightly larger than the values determined experimentally;132-139 HF/6-31G* and MP2/6-31G* structures again are in better agreement.⁴⁹ The eclipsed form 7 is found to be 1.0 kcal/mol higher in energy; this agrees with the experimental rotational barrier of 1.06 kcal/mol.¹³²⁻¹³⁴ In this structure, the C-O bond length increases to 1.455 Å and the C-O-H bond angle increases to 111.1°.

Silanol, H₃SiOH, is unstable toward disproportionation and has never been isolated experimentally:140

$$2H_3SiOH \rightarrow H_3SiOSiH_3 + H_2O$$

The HF/3-21G^(*) equilibrium structure of H₃SiOH has been reported recently.141 The Si-O bond length, 1.633 Å, is in excellent agreement with the experimental distance of 1.63 Å in the diol and triol.¹⁴² The Si-O-H bond angle, 128.8°, is much larger than the C-O-H angle in methanol. This and the longer Si-O bond length help to reduce the rotational barrier to 0.4 kcal/mol. In the eclipsed structure 7, the Si-O-H bond angle increases to 130.4°

In agreement with photoelectron spectra,¹⁴³ the ordering of the valence orbitals in H₃CSH and H₃SiSH is the same. This is also true of methanol and silanol. The staggered form 6 of methyl mercaptan has a C-S bond distance⁸ of 1.822 Å, in good agreement with the experimental values of 1.819144 and 1.818 Å145 and the HF/4-31G* separation of 1.815 Å.125 The C-S-H bond angle is small, 97.6°; experiments give 96.5°144 and 110.3°.145 The C-S distance, larger than the C-O bond length, compensates for the smaller angle at sulfur and yields a rotational barrier of 1.1 kcal/mol in H_3CSH , approximately the same as that in methanol. The experimental barrier is 1.27 kcal/mol.^{104,144} The eclipsed structure 7 has a C-S bond length of 1.831 Å and a C-S-H angle of 98.0°, both values are slightly larger than in 6.

Silyl mercaptan, H₃SiSH, characterized calculationally by Glidewell,¹⁴⁶ may result from the reaction of disilyl sulfide with

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Table III. HF/3-21G(*) Optimized Si-H and Si-X Bond Lengths and H-Si-X Bond Angles for All H₃SiXH_n Molecules^a

XH _n	r(Si-H) ^b	θ(H-Si-X) ^c	$r(Si-X)^b$	$\Delta r(Si-X)^d$
Н	1.475	109.5	1.475	0.012
Li	1.495	115.1	2.542	-0.011
BeH	1.483	111.8	2.204	-0.009
BH_2	1.479	110.7	2.025	0.013
CH ₃	1.478	110.6	1.883	0.034
NH_2	1.478	111.2	1.710	0.032
OH	1.468	110.5	1.633	0.042
F	1.469	109.1	1.593	0.042
Na	1.496	115.2	2.837	-0.002
MgH	1.486	112.8	2.607	0.005
AlH_2	1.481	111.5	2.467	0.014
SiH	1.477	110.3	2.342	0.041
PH,	1.475	109.8	2.256	0.091
SH	1.471	109.2	2.139	0.116
Cl	1.467	108.5	2.056	0.135

"When more than one distinct H-Si-X angle is present, the average value is reported. ^b Distances are in angstroms. ^c Angles are in degrees. ^d This difference is the HF/3-21G optimized bond length minus the HF/3-21G^(*) separation (caused by adding d-functions to the secondrow atoms), in angstroms.

hydrogen sulfide.¹⁴⁷ No experimental structures are available. The staggered form 6 of this molecule has a Si-S bond length of 2.139 Å. The Si-S-H bond angle is 98.2°, slightly larger than the bond angle in H₃CSH. The greater bond length to the sulfur results in a lower rotational barrier in silyl mercaptan (0.9 kcal/mol) than in H₃CSH. The Si-S bond length in eclipsed 7 increases to 2.147 Å; the increase in H₃CSH is virtually the same.

H₃CF, H₃SiF, H₃CCl, and H₃SiCl. The valence orbital ordering, the same in H₃CF, H₃SiF, H₃CCl, and H₃SiCl, agrees with earlier results on silyl chloride¹⁴⁸ and methyl chloride.¹⁴⁹ The degenerate HOMO with e symmetry corresponds to nonbonding halogen orbitals. Orbitals of a₁ symmetry, representing the heavy-atomheavy-atom bond, are lower in energy. In methyl fluoride, the C-F bond distance (1.404 Å) is longer than the experimental value of 1.385 Å, while the calculated H-C-F bond angle, 109.4°, is slightly larger than experiment $(108.3-109.4^{\circ})$.¹⁵⁰⁻¹⁵² In H₃SiF, the Si-F bond distance of 1.593 Å^{8,153} is essentially identical with experiment (1.594 Å).¹⁵⁴⁻¹⁵⁶ The H-Si-F bond angle, 109.1°, also is in good agreement. In methyl fluoride, the p-orbitals on the fluorine perpendicular to the C-F axis contain 1.957 electrons, showing only a slight interaction with the C-H bonds. In silyl fluoride, these p-orbitals contain 1.897 electrons, suggesting a larger interaction.

The H-C-Cl angle in H₃CCl is 108.7°, smaller than in H₃CF. The C-Cl bond length, 1.806 Å,8 is longer than experiment.¹⁵⁷⁻¹⁵⁹ In silyl chloride, the Si–Cl separation, 2.056 Å, is only slightly longer than experiment.^{160–162} The H–Si–Cl bond angle, 108.5°,

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Table IV. HF/3-21G^(*) (HF/3-21G for Methyl First-Row Molecules) Optimized C-H and C-X Bond Lengths and H-C-X Bond Angles for All H₃CXH, Molecules^a

XH _n	<i>r</i> (C-H) ^{<i>b</i>}	$\Theta(H-C-X)^{c}$	r(C-X) ^b	$\Delta r(C-X)^d$
Н	1.083	109.5	1.083	
Li	1.094	111.9	2.001	
BeH	1.090	111.7	1.713	
BH_2	1.089	111.4	1.577	
CH ₃	1.084	110.8	1.542	
NH_2	1.085	110.9	1.472	
OH	1.083	110.3	1.440	
F	1.080	109.4	1.404	
Na	1.091	110.6	2.315	0.005
MgH	1.090	111.5	2.104	0.008
AlH_2	1.089	111.4	1.974	0.015
SiH ₃	1.087	111.0	1.883	0.034
PH_2	1.084	110.5	1.856	0.053
SH	1.080	109.7	1.822	0.072
C1	1.076	108.1	1.806	0.086

"When more than one distinct H-C-X angle is present, the average value is reported. ^bDistances are in angstroms. ^cAngles are in degrees. ^d This difference is the HF/3-21G optimized bond length minus the HF/3-21G(*) separation (caused by adding d-functions to the secondrow atoms), in angstroms.

also is smaller than the H-C-Cl angle in the carbon analogue. The atomic charge on the fluorine is -0.41 in H₃CF and -0.43in H_3SiF . As expected, the negative charge on the chlorine is smaller in H_3CCl (-0.11) than in H_3SiCl (-0.41).

Discussion

Structural Features and Trends. The 3-21G(*) optimized Si-H bond lengths and H-Si-X bond angles for the H₃SiXH_n molecules, listed in Table III, can be compared with the corresponding bond lengths and angles for the H_3CXH_n molecules (Table IV). The Si-H distances and H-Si-X bond angles tend to decrease on moving from left to right across either the first or second row of the periodic table. A similar trend is found for the saturated methyl species. The only definite inconsistency is silylamine; the H-Si-N bond angle is larger than the H-Si-C angle found in the equilibrium structure of methylsilane. This larger H-Si-N angle is most likely due to the unusual structure of silylamine, with a planar arrangement at nitrogen. The H-Si-X bond angles are found to be larger for X = N, O, and F than for the second-row element of the same group. This is also true for the H-C-X bond angles, and indicates the influence of the electronegativity of the substituent.

Table V compares the geometries of the XH_n groups with methyl and silyl substituents. Generally, replacing the methyl group with a silyl group does not change the geometry at the X atom. The only exceptions are for $XH_n = NH_2$ and OH. As stated above, the equilibrium structure of methylamine has a nonplanar structure at nitrogen, but is planar in silylamine. In the staggered form (6) of methanol, the C–O–H bond angle is 110.4°, while in silanol, the Si-O-H angle is 128.8°. Both the N-H and O-H bond lengths are smaller in the silvl than the methyl compounds. An increase in the s-character of the σ -bond orbital involving nitrogen or oxygen due to the lower electronegativity of silicon is responsible.

The last two columns of Tables III and IV list the heavyatom-heavy-atom bond lengths obtained with the 3-21G(*) basis set and also the change in this distance caused by adding dfunctions to the second-row atoms. These d-functions generally decrease the bond lengths. The only exceptions are Si-Li, Si-Be, and Si-Na; the $3-21G^{(*)}$ bond lengths are slightly longer than those at 3-21G. The bond length decrease becomes greater as the electronegativity of the atoms increases. The decrease is much larger between two second-row atoms, both of which have dfunctions added, than between a first- and second-row atom. In the few cases where experimental structures are available, the

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Table V. Optimized Bond Lengths to Hydrogen and Bond Angles Involving the Heavy Atom Bound to Either Carbon or Silicon in the Equilibrium Structures of H₃CXH_n and H₃SiXH_n Molecules^a

	H ₃ CXH _n			H ₃ SiXH _n		
XH _n	$\overline{r(X-H)^b}$	Ө(С-Х-Н)	θ(H-X-H) ^c	$r(X-H)^b$	θ(Si-X-H)	$\Theta(H-X-H)^c$
BeH	1.341	180.0		1.341	180.0	,
BH ₂	1.192	121.1	117.8	1.191	121.5	117.0
CH	1.080	110.8	108.1	1.087	111.0	107.9
NH,	1.004	113.6	111.1	1.001	123.3	113.4
ОН	0.966	110.4		0.959	128.8	
MgH	1.729	180.0		1.726	180.0	
AlH ₂	1.592	120.8	118.4	1.590	120.7	118.6
SiH	1.478	110.6	108.3	1.477	110.3	108.6
PH,	1.403	98.3	94.6	1.403	96.8	95.1
SH	1.327	97.6		1.329	98.2	

^a For the methyl first-row molecules, the 3-21G basis set was used while 3-21G^(*) results are listed in all other cases. ^bDistances are in angstroms. ^cAngles are in degrees.

Table VI. Heats of Reaction (ΔH) for the Exchange between H₃Si-X and H₃C-X (Equation 1), Experimental H₃C-X Bond Energies, and Theoretical and Experimental H₃Si-X Bond Strength^a

x	$\Delta H_{\rm rxn}{}^b$	$exptl D^{\circ}_{298.15}(H_{3}C-X)^{c}$	theory ^d (exptl) $D(H_3Si-X)$
Н	-14.5	105.1 ± 0.2	90.6 (90.3) ^e
Li	6.2	39.2	45.4
BeH	-14.8		
BH ₂	-19.6	f	
CH,	-4.9	90.4 ± 0.3	85.5 (82.1) ^g
NH_2	13.8	84.9 ± 1.1	98.7 (100) ^h
ОΗ	26.6	92.3 ± 1	$(128)^i (108)^j$
F	37.9	109.9 ± 1	147.8 (135) ^j
Na	8.3		
MgH	-1.6		
AIH_2	-10.7	f	
SiH ₃	-11.5	82.1 ± 3	70.6 (74) ^e (53) ^j
PH_2	-2.5	f	
SH	9.1	74.0 ± 3	83.1 (70?) ^j
C1	20.3	84.6 ± 0.2	104.9 (113) ⁱ (91) ^j

^aAll energies are in kcal/mol. ^bCalculated from MP4/6-31G* energies, corrected for zero-point energy differences. 'Except where noted, data are from D. F. McMillen and D. M. Golden, Annu. Rev. Phys. Chem., 11, 493 (1982). ^dCalculated by adding the energies of columns 2 and 3. From ref 163a. Average bond strengths for trimethyl compounds are available in A. Pilcher and H. A. Skinner in "The Chemistry of the Carbon-Metal Bond", S. Patai, Ed., Wiley, New York, 1982. ^g From the reference in footnote c. ^h From (CH₃)₃-Si-NHCH₃, ref 163a. ¹From (CH₃)₃Si-X, ref 163a. ¹From ref 163b.

 $3-21G^{(*)}$ results are always found to be in better agreement than the3-21G geometries. This is the general experience.⁸

H₃Si-X Bond Strengths. Reliable bond dissociation energies are essential for the interpretation of the kinetics and mechanisms of the reactions of silicon compounds. Unfortunately, accurate thermodynamic data for silicon molecules are sparse, and only a few Si-X bond energies are known.¹⁶³ Furthermore, in most cases the available data are derived from polysubstituted systems (e.g., $(CH_3)_3SiX$),¹⁶³ where the effects of the additional substituents complicate the analysis, and not from the parent H_3SiX .

At the level of theory used here, directly calculated bond energies are not accurate. Much better values may be obtained indirectly. With the energies in Tables I and II, it is possible to compare the relative Si-X and C-X bond strengths in saturated silyl and methyl species by examining the enthalpy change in the isogyric reaction in which the spin multiplicity is conserved:

$$H_{3}SiX + CH_{3} \rightarrow SiH_{3} + H_{3}CX$$
(1)

These heats of reaction, calculated by using the MP4SDTQ/6-31G* energies, corrected for zero-point vibrational energies, are listed in the second column of Table VI. From the first entry, it is clear that the C-H bond in methane is stronger than the Si-H bond in silane by 14.5 kcal/mol.



Figure 1. Plot of the heats of reaction for exchange between H_3Si-XH_n and H₃C-XH_n vs. the Allred-Rochow electronegativity of atom X. The energies are the negative of the values in Table VI.

Figure 1, a plot of these data against Allred-Rochow electronegativities,164 reveals that about half of the C-X bonds are stronger than the corresponding Si-X bonds. Two inverted Vshaped curves, one for first-row and the other for second-row substituents, are found, but these merge on the electropositive side. The Si-Li and Si-Na bonds are stronger than their carbon counterparts. The electron affinity of SiH₃ is much greater than CH₃ (which is near zero),¹⁶⁵ and largely ionic bonds involving $SiH_3^-X^+$ ion pairs are better than $CH_3^-X^+$.

Although the bonds are less ionic, the same trend in Si-X vs. C-X bond strengths is found when the substituents contain the more electronegative elements in each period (F, OH, NH₂, as well as Cl and SH). The ionization potential of SiH₃ is less than that of CH₃ by 2.3 eV.¹⁶⁶ Thus, H₃Si⁺-X⁻ character is favored over H₃C⁺-X⁻. The ambielectronic nature of SiH₃ is thus responsible for the inverted V's of Figure 1.

The substituents with electronegativities closer to silicon have stronger bonds to carbon. With H, BeH, BH₂, AlH₂, and SiH₃, the differences favoring C-X are in the 10-20 kcal/mol range; the preferences involving $X = CH_3$ (4.9 kcal/mol) and PH₂ (2.5 kcal/mol) are smaller.

Values of H₃Si-X bond energies can now be determined by using experimental H₃C-X bond strengths. The experimental

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Figure 2. Plot of the calculated H_3Si-XH_n bond strengths vs. the All-red-Rochow electronegativity of atom X.

values are listed in the third column of Table VI, and when combined with the heats of reaction of eq 1 yield the H₃Si-X bond energies listed in the fourth column of Table VI. These results are in fair agreement with the few available experimental bond energies; studies on simple hydrides have shown that both basis set expansion and extrapolation of the Møller–Plesset series to infinite order are necessary to obtain accurate bond strengths.²⁴ When these values are plotted against Allred–Rochow electronegativities (Figure 2), a correspondence emerges. As the electronegativity of X increases, so does the Si–X bond strength.

It has been argued that $d-\pi$ conjugation, for example in H₃SiNH₂, involving good π -donor substituents and vacant d-orbitals on silicon might contribute to the strengthening of silicon bonds.¹⁶⁷ On the other hand, the correlation in Figure 2 argues strongly that the major factor determining the strength of single bonds to silicon is the electronegativity of the group X. Stronger bonds are formed with more electronegative groups because of greater contributions from ionic structures of the type H₃Si⁺X⁻. The fact that bonds between silicon and substituents of similar electronegativity but different chemical character have very similar dissociation energies argues against the importance of $d-\pi$ bonding. Thus $D(H_3Si-SH) \sim D(H_3Si-CH_3)$, although sulfur has lone pairs that can participate in $d-\pi$ conjugation and the methyl group does not. In addition, Mislow has concluded that $(p-d) \pi$ conjugation need not be invoked to explain the decrease in amine inversion barriers when silicon-based substituents are present.¹⁶⁸ The isoelectronic $H_3SiCH_2^-$ carbanion is strongly stabilized relative to CH₃, but we have shown recently that $(p-d) \pi$ conjugation can only be a very minor contributor.¹⁶⁹

We stress, however, in agreement with previous workers, 170 that it is difficult to separate $d-\pi$ bonding effects from ionic contributions. A more elaborate study is needed to determine the relative importance of various factors such as ionicity, $d-\pi$ conjugation, and orbital overlap in determining the strength of bonds to silicon.

The BH₂-F and SiH₃-Cl lines of Figure 1 are roughly parallel but are displaced from one another by about 15 kcal/mol Thus, for a given electronegativity, Si-X bonds to first-row groups are generally weaker than C-X bonds by this amount. This may be due to poorer first-row-second-row σ -overlap. Bonds tend to be stronger when they are between elements of the same row.^{68b}

Conclusions

There are definite similarities between the structures of silyl and methyl derivativies. The only exceptions are H_3SiNH_2 and H_3SiOH , where greater bond angles are found at nitrogen and oxygen than in the corresponding methyl compounds. The lower hydrides of silicon favor states which have nonbonding electrons in silicon orbitals with a large degree of s-character, more than in the carbon analogues. This results in a greater separation between the ²II and ⁴ Σ ⁻ states in SiH than in CH and accounts for a singlet state having the lowest energy in SiH₂, smaller H–Si–H bond angles, and a nonplanar structure of SiH₃. This requirement also plays a major role in the structure of unsaturated silicon molecules.⁵⁴

The addition of *d*-functions to second-row molecules often reduces the bond lengths. In all cases, the optimized $3-21G^{(*)}$ geometries are in better agreement with available experimental structures than the 3-21G geometries.

The results presented in Figures 1 and 2 show that the relative energies of H_3Si-X and H_3C-X bonds are mainly influenced by the electronegativity of the group X. Groups with either a very high or a very low electronegativity are found to make stronger bonds to silicon than to carbon. There does not appear to be any support to the contention that the bonds to silicon are strengthened or bond angles widened by π -donation into vacant d-orbitals.

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Registry No. SiH, 13774-94-2; SiH₂, 13825-90-6; SiH₃, 13765-44-1; SiH₄, 7803-62-5; H₃SiLi, 14311-51-4; H₃SiBeH, 98921-84-7; H₃SiBH₂, 14809-30-4; H₃SiCH₃, 992-94-9; H₃SiNH₂, 13598-78-2; H₃SiOH, 14475-38-8; H₃SiF, 13537-33-2; H₃SiNa, 16693-29-1; H₃SiMgH, 98921-85-8; H₃SiAlH₂, 56697-79-1; H₃SiSiH₃, 1590-87-0; H₃SiPH₂, 14616-47-8; H₃SiSH, 14044-97-4; H₃SiCl, 13465-78-6; CH, 3315-37-5; CH₂, 2465-56-7; CH₃, 2229-07-4; CH₄, 74-82-8; H₃CLi, 917-54-4; H₃CBeH, 6917-55-1; H₃CBH₂, 12538-96-4; H₃CCH₃, 74-84-0; H₃CN-H₂, 74-89-5; H₃COH, 67-56-1; H₃CF, 593-53-3; H₃CNa, 18356-02-0; H₃CMgH, 63533-51-7; H₃CAlH₂, 27140-10-9; H₃CPH₂, 593-54-4; H₃CSH, 74-93-1; H₃CCI, 74-87-3.

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